## 

## **U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	Α	US-2002/0156953	10-2002	Beiley et al.	710/105
*	В	US-2003/0041223	02-2003	Yeh et al.	711/167
*	С	US-2003/0158981	08-2003	LaBerge, Paul A.	710/100
*	D	US-6,584,526	06-2003	Bogin et al.	710/124
*	Ε	US-5,630,106	05-1997	Ishibashi, Shohzoh	345/533
*	F	US-6,584,572	06-2003	Choi, Jung-hwan	713/320
*	G	US-6,671,212	12-2003	Macri et al.	365/189.07
*	Н	US-2004/0068594	04-2004	Asaro et al.	710/104
	l	US-			
	J	US-			
	К	US-			
	L	US-			
	М	US-			

## FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	0					
	Р			0. 1		
	Q					
	R					
	s					
	T					

## **NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	A 500-MHz 4-Mb CMOS Pipeline-Burst Cache SRAM with Point-to-Point Noise Reduction Coding I/O
	٧	
	w	
	x	

<sup>\*</sup>A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.